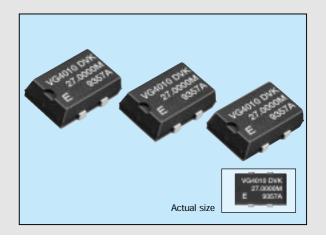
## **VOLTAGE-CONTROLLED CRYSTAL OSCILLATOR**

# **'G-4000 series**

- High accuracy and high reliability due to trimmerless design.
- Built-in heat resistive AT-cut crystal provides heat resistance equivalent to that of general-purpose ICs.
- Use of C-MOS IC assures low current consumption.
- · Excellent shock resistance and environmental capability.
- Supply voltage: 5V(VG-4010JA) • Supply voltage: 3.3V(VG-4030JA)



## **■** Specifications (characteristics)

ltem		Symbol	VG-4010JA DVK	VG-4030JA DVK	
			Specifications		Remarks
Output frequency range		fo	2.0000 MHz to 28.63636 MHz		*
Power source voltage	Max. supply voltage	VDD-GND	-0.5V to +7.0V		
	Operating voltage	V <sub>DD</sub>	5.0V ±0.25V	3.3V ±0.17V	
Temperature range	Storage temperature	Тѕтс	-55°C to	+125°C	
	Operating temperature	Topr	-20°C to + 70°C(-40°C to + 85°C)		
Soldering condition		TsoL	Twice at under 260°C within 10 sec.		
Frequency stability		$\Delta f/f_0$	±35ppm max.	±37ppm max.	VC=0.5 to 4.5V(4010JA) / VC=0.0 to 3.0V(4030JA)
Current consumption		lop	35mA max.	18mA max.	No load condition
Pull range		∆fc	±75ppm	As per below table	VC=0.5 to 4.5V(4010JA) / VC=0.0 to 3.0V(4030JA)
Input resistance		Zin	10MΩ min.		DC Level
Frequency change polarity			Positive polarity		VC=0.5 to 4.5V(4010JA) / VC=0.0 to 3.0V(4030JA)
Duty		tw/t	45% to 55%(40% to 60%)	40% to 60%	1/2VDD level(1.4V level)
Output voltage		Vон	V <sub>DD</sub> -0.4V min.		Iон= -0.8mA
		Vol	0.4V max.		IoL=3.2mA
Output load condition (fan out)		N/CL	2TTL or 30pF max.	30pF max.	TTL load/C-MOS load
Output rise time		<b>t</b> TLH	5ns. max.	6ns. max.	C-MOS load: 20%→80% Vpp level
			8ns. max.	_	TTL load: 0.4V→2.4V level
Output fall time		tтнL	5ns. max.	6ns. max.	C-MOS load: 20%→80% Vpp level
			8ns. max.	_	TTL load: 0.4V→2.4V level
Oscillation start up time		tosc	10ms. max.		Time at minimum operating voltage to be 0 sec.
Aging		fa	±5ppm max.		Ta=25°C, first year
Shock resistance		S.R.	±10ppn	n max.	Three drops on a hard board from 75 cm or excitation test with 3000G x 0.3ms x 1/2sine wave in 3 directions

Vc should be "GND" or "OPEN" when power is on.

### **External dimensions**

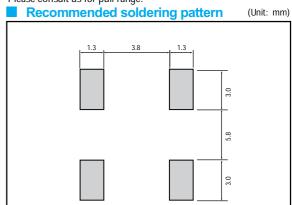
(Unit: mm)

## #3 Vc GND **VG4010 DVK** OUT 27.0000M 9357A 14.0 max. 0.51

## Pull range

Pull range	Remarks		
180ppm	Crystal unit's frequency < 20MHz, Vc=0.0 to 3.0V		
150ppm	Crystal unit's frequency ≥ 20MHz, Vc=0.0 to 3.0V		

Please consult us for pull range.



<sup>\*</sup> Please contact us for inquiries about the available frequency.

## THE CRYSTALMASTER

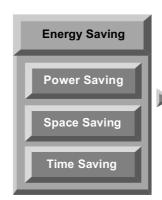


EPSON offers effective savings to its customers through a wide range of electronic devices, such as semiconductors, liquid crystal display (LCD) modules, and crystal devices. These savings are achieved through a sophisticated melding of three different efficiency technologies.

Power saving technology provides low power consumption at low voltages.

Space saving technology provides further reductions in product size and weight through super-precise processing and high-density assembly technology.

Time saving technology shortens the time required for design and development on the customer side and shortens delivery times.



Our concept of Energy Saving technology conserves resources by blending the essence of these three efficiency technologies. The essence of these technologies is represented in each of the products that we provide to our cus-

In the industrial sector, leading priorities include measures to counter the greenhouse effect by reducing CO2,

measures to preserve the global environ-

ment, and the development of energyefficient products. Environmental problems are of global concern, and although the contribution of energysaving technology developed by EPSON may appear insignificant, we seek to contribute to the develop-

ment of energy-saving products by our

customers through the utilization of our electronic devices. EPSON is committed to the conservation of energy, both for the sake of people and of the planet on which we live.





Resource

Saving



SEIKO EPSON CORP. QUARTZ DEVICE DIVISION acquired ISO9001 and ISO14001 certification by B.V.Q.I. (Bureau Veritas Quality International) . ISO9001 in October, 1992. ISO14001 in November, 1997.

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